imall

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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Low VF Schottky Diode

- Reverse voltage: 40 V
- Forward current: 0.2 A
- Low forward voltage and smallest package form factor (1.0 x 0.6 x < 0.4 mm) for mobile phone battery charger application
- Pb-free (RoHS compliant) package



BAS4002S-02LRH



Туре	Package	Configuration	Marking
BAS4002S-02LRH	TSLP-2-17	single	2A

Maximum Ratings at T_A = 25 °C, unless otherwise specified

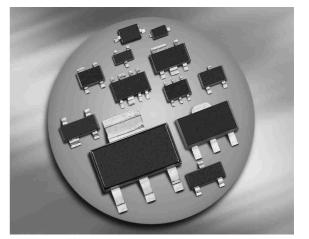
Parameter	Symbol	Value	Unit
Diode reverse voltage ¹⁾	V _R	40	V
Forward current ¹⁾ , $T_{S} \le 138 \text{ °C}$	I _F	0.2	A
Non-repetitive peak surge forward current	/ _{FSM}	2	
(<i>t</i> ≤ 10 ms)			
Junction temperature	Ti	150	°C
Operating temperature range	T _{op}	-55150	
Storage temperature	T _{stg}	-65150	

Thermal Resistance

Junction - soldering point ²⁾	R _{thJS}	≤ 60	K/W

¹For $T_A > 25$ °C the derating of V_R and I_F has to be considered.

 $^2 \rm For}$ calculation of $R_{\rm thJA}$ please refer to Application Note Thermal Resistance





Parameter	Symbol	Values			Unit
		min.	typ.	max.]
DC Characteristics					
Reverse current ¹⁾	I _R				μA
V _R = 5 V		-	-	0.5	
<i>V</i> _R = 10 V		-	-	1	
V _R = 40 V		-	-	10	
Forward voltage ¹⁾	V _F				mV
<i>I</i> _F = 0.1 mA		-	210	250	
/ _F = 1 mA		-	270	310	
/ _F = 10 mA		-	330	370	
/ _F = 100 mA		-	420	470	
<i>I</i> _F = 200 mA		-	470	550	
AC Characteristics		, <u> </u>	,		
Diode capacitance	CT	-	7	12	pF
<i>V</i> _R = 5 V, <i>f</i> = 1 MHz					
1 Pulsed test: $t = 300 \text{ us}$ $D = 0.01$					

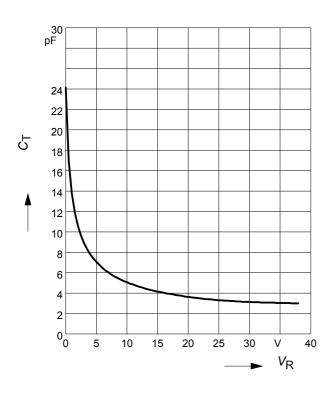
Electrical Characteristics at $T_A = 25^{\circ}$ C, unless otherwise specified

¹Pulsed test: t_p = 300 µs, *D* = 0.01



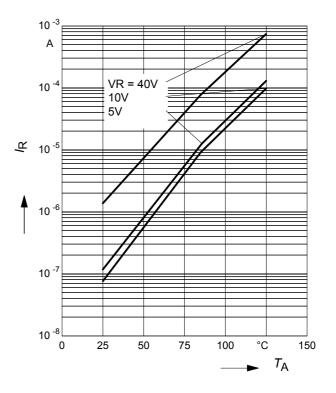
Diode capacitance $C_{T} = f(V_{R})$

f = 1 MHz



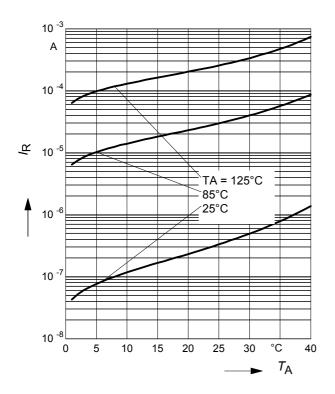
Reverse current $I_{R} = f(T_{A})$

 $V_{\rm R}$ = Parameter



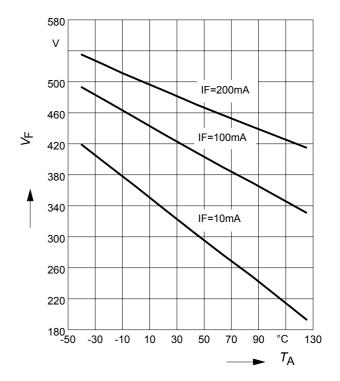
Reverse current $I_{R} = f(V_{R})$

 T_A = Parameter



Forward Voltage $V_{\rm F}$ = $f(T_{\rm A})$

 $I_{\rm F}$ = Parameter



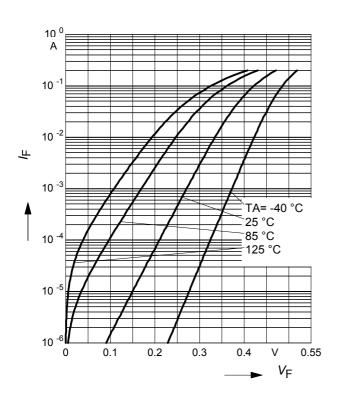


Forward current $I_F = f(V_F)$

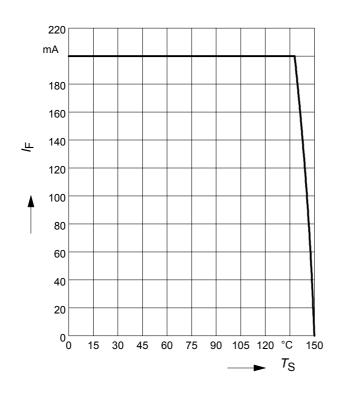
Permissible Reverse voltage $V_R = f(T_A)$

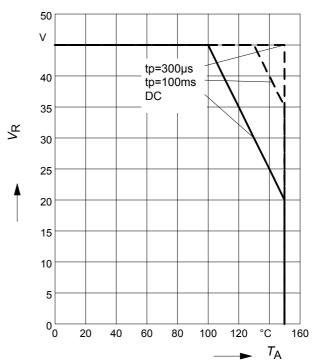
 t_p = Paramter, Duty cycle < 0.01

Device mounted on PCB with $R_{\rm th}$ = 160 K/W

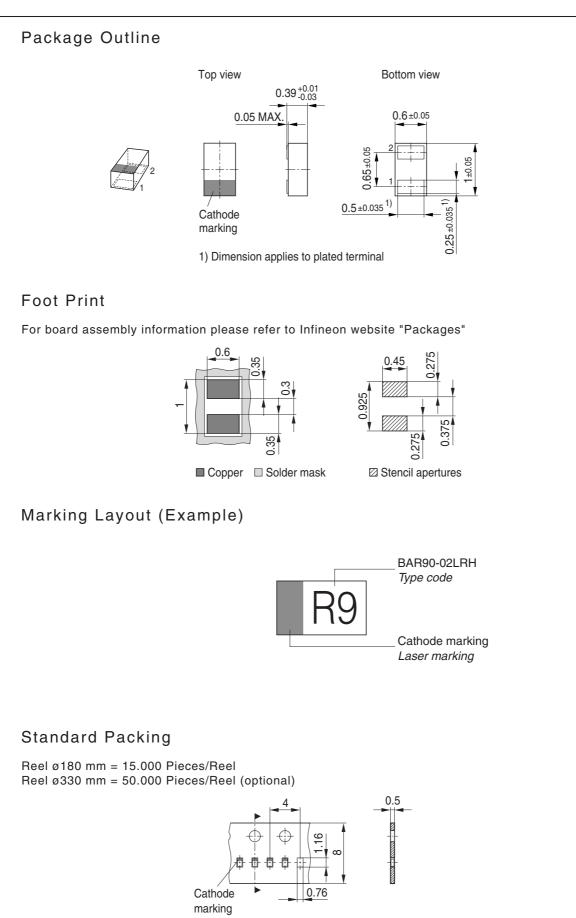


Forward current $I_{F} = f(T_{S})$ BAS4002S-02LRH











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